

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Khan et al.

Title: METAL OXIDE SEMICONDUCTOR HETEROSTRUCTURE FIELD EFFECT
TRANSISTOR

Commissioner for Patents
Alexandria, VA 22313-1450

PRELIMINARY AMENDMENT

Dear Sir:

Prior to initial examination on the merits and calculation of the filing fee, please enter the following amendments:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims that begins on page 4 of this paper.

Amendments to the Drawings begin on page 9 of this paper and include both an attached replacement sheet and a marked up sheet showing the changes made.

Remarks begin on page 10 of this paper.

An Appendix including the amended drawing figures is attached following page 10 of this paper.